BGA619

Silicon Germanium High IP3 PCS Low Noise Amplifier

Wireless Silicon Discretes



Never stop thinking.

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| BGA619 Data Sho Revisior | | April 2004 |
|--------------------------------|------------|------------------------------------|
| Previous | Version: | February 2004 |
| Page | Subjects (| major changes since last revision) |
| 4 | Marking c | orrected |
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Silicon Germanium High IP3 PCS Low Noise Amplifier

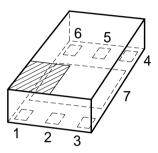
BGA619

Features

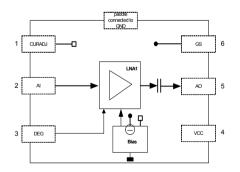
- B7HF silicon germanium technology
- Tiny P-TSLP-7-1 leadless package
- RF output-port internally pre-matched to 50Ω
- Low external component count
- · Three gain steps
- Power off function
- · High IP3 in all modes
- Typical supply voltage: 2.78 V

Applications

• 1.9 GHz PCS wireless frontends (CDMA2000)



P-TSLP-7-1



Description

The BGA619 is a high IP3 PCS low noise amplifier, designed for 1.9GHz applications.

Internal biasing provides stabile current conditions for all gain modes over temperature range.

Using the pin GS the BGA619 can be switched between three gain modes (HIGH, MID & LOW) and the OFF mode.

ESD: Electrostatic discharge sensitive device, observe handling precaution!

| Туре | Package | Marking | Chip |
|--------|------------|---------|-------|
| BGA619 | P-TSLP-7-1 | BT | T1544 |



Pin Definition and Function

| Pin No. | Symbol | Function | |
|---------|--------|--------------------|--|
| 1 | CURADJ | Current adjust LNA | |
| 2 | AI | LNA input | |
| 3 | DEG | RF ground | |
| 4 | VCC | Supply voltage LNA | |
| 5 | AO | LNA output | |
| 6 | GS | Gain step control | |
| 7 | GND | Ground | |

Maximum Rating

| Parameter | Symbol | Limit value | Unit |
|--|---------------------|--|------|
| Voltage at pin VCC | VCC | -0.3 3.6 | V |
| Voltage at pin AI (LNA input) | AI | -0.3 (min.) | V |
| Voltage at pin AO (LNA output) | AO | -0.3 V _{VCC} +0.3 3.6 (max.) | V |
| External resistor | R _{CURADJ} | 6 (min.) | kΩ |
| Current into VCC | ICC | 11 | mA |
| Junction temperature | Tj | 150 | °C |
| Ambient temperature range | T _A | -35 85 | °C |
| Storage temperature range | T _{STG} | -40 150 | °C |
| ESD capability (HBM: JESD22A-114) RF pin Al all other pins | V _{ESD} | <500 1000 | V |

Notes: All Voltages refer to GND-Node



Electrical Characteristics

 $T_A=25^\circ\text{C}:$ VCC=2.78V , $R_{\text{LNA}_\text{Curadj}}$ = $15k\Omega,$ frequency=1.96GHz, HIGH: GS=2.3V, MID: GS=1.7V, LOW: GS=1.0V, unless otherwise noted; measured on BGA619 Appl. Board V1.0 including PCB losses

| Parameter | Symbol | GS mode | min. | typ. | max. | Unit |
|--|------------------------|---------------------------|--------------------------|--------------------------|--------------------------|----------|
| Supply current | I _{cc} | HIGH MID LOW OFF | | 6.5 4.5 2.9 280 | | mA μA |
| Power gain | S ₂₁ | HIGH MID LOW | | 14.9 2.2 -9.5 | | dB |
| Noise figure (Zs = 50Ω) | NF | HIGH MID LOW | | 1.5 8 16 | | dB |
| Input Return Loss | S ₁₁ | HIGH MID LOW | | 10.5 8.5 12.5 | | dB |
| Output Return Loss | \$ ₂₂ | HIGH MID LOW | | 11.5 13 13 | | dB |
| Reverse isolation | S ₁₂ | HIGH MID LOW | | 25 21 23 | | dB |
| Power gain settling time (within 1dB of the final gain) | t _s | ALL | | 70 | | μS |
| 3rd order input intercept point f1= 1950MHz, f2= f1 +/-1MHz P(f1,f2)= -30dBm P(f1,f2)= -27dBm P(f1,f2)= -15dBm | IIP ₃ | HIGH MID LOW | | 7 6.5 15 | | dBm |
| Gain step input voltage | GS | HIGH MID LOW OFF | 2.2 1.6 0.9 0.0 | | 2.4 1.8 1.1 0.3 | V |
| Gain control current | I _{GS} | HIGH OFF | | | 95 -55 | μA |

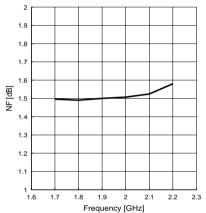




Typical measurement results HIGH Gain Mode; T_A = 25°C

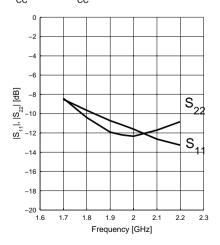
Gain $|S_{21}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 6.5mA$ 18 17 -30°C 16 [gp] |¹⁵ S 25°C 14 13 +85°C 12 1.6 1.7 1.8 1.9 2 2.1 2.2 2.3 Frequency [GHz]

Noise Figure NF = f(f) $V_{CC} = 2.78V$, $I_{CC} = 6.5mA$, Gain = 14.9dB



Reverse Isolation $|S_{12}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 6.5 \text{m}\text{\AA}$ 0 -5 -10 -15 [gp] |²¹ S -25 -30 -35 -40 1.7 2.1 2.2 2.3 1.6 1.8 1.9 2 Frequency [GHz]

 $\begin{array}{ll} \mbox{Matching} & |S_{11}|, \, |S_{22}| = f(f) \\ \mbox{V}_{CC} = 2.78 \mbox{V}, \, \mbox{I}_{CC} = 6.5 \mbox{mA} \end{array}$

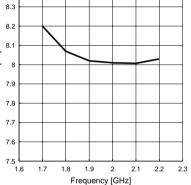




Typical measurement results MID Gain Mode; T_A = 25°C

Gain $|S_{21}| = f(f)$ Noise Figure NF = f(f) $V_{CC} = 2.78V, I_{CC} = 4.5mA$ 8.5 -30°C 8.4 4 8.3 8.2 3 8.1 25[°]C |S₂₁| [dB] NF [dB] 2 8 7.9 1 7.8 7.7 0 +85°C 7.6 -1 7.5 2.2 2.3 1.6 1.7 1.8 1.9 2 2.1 1.6 1.7 1.8 1.9 Frequency [GHz] Reverse Isolation $|S_{12}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 4.5mA$ **Matching** $|S_{11}|, |S_{22}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 4.5mA$ 0 0 -2 -5 -4 -10 -6 -15 [g] -8 -10 -12 -12 -12 [gp] |²⁰-20 -25 -14 -30 -16 -35 -18 -40 -20 1.6 1.7 1.8 1.9 2 2.1 2.2 2.3 1.6 1.7 1.8 1.9 Frequency [GHz] Frequency [GHz]

 $V_{CC} = 2.78V, I_{CC} = 4.5mA, Gain = 2.2dB$



 \overline{S}_{11}

S_22

2.1 2.2 2.3

2

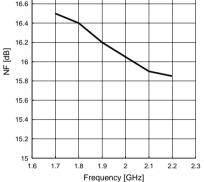




Typical measurement results LOW Gain Mode; T_A = 25°C

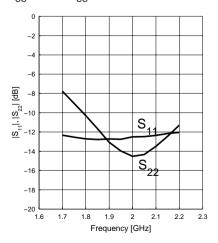
Gain $|S_{21}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 2.9mA$ -7 30°C -8 25°C -9 [S]-10 S]-10 -11 +85°C -12 -13 1.6 1.7 1.8 1.9 2 2.1 2.2 2.3 Frequency [GHz]

Noise Figure NF = f(f) $V_{CC} = 2.78V, I_{CC} = 2.9mA, Gain = -9.5dB$



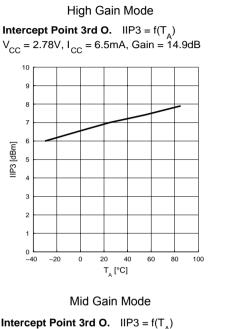
Reverse Isolation $|S_{12}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 2.9mA$ 0 -5 -10 -15 [gp] |²⁰ S¹² | -25 -30 -35 -40 1.6 1.7 1.8 1.9 2 2.1 2.2 2.3 Frequency [GHz]

Matching $|S_{11}|, |S_{22}| = f(f)$ $V_{CC} = 2.78V, I_{CC} = 2.9mA$

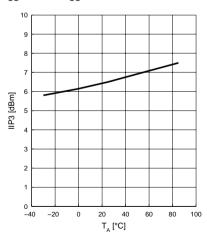




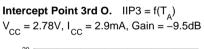
Typical measurement results 3rd Order Intercept Point

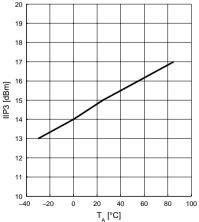


Intercept Point 3rd O. IIP3 = $f(T_A)$ V_{CC} = 2.78V, I_{CC} = 4.5mA, Gain = 2.2dB



Low Gain Mode



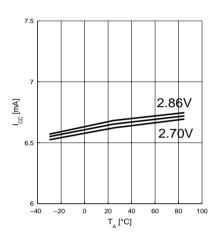




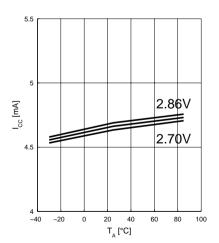
Typical measurement results Supply Current vs.Temp & Supply (2.7..2.78..2.86V)

HIGH Gain Mode

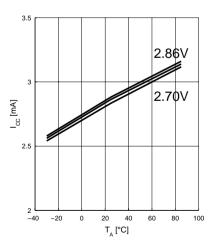
Supply current vs. Temp. $I_{CC} = f(T_A, V_{CC})$



MID Gain Mode Supply current vs. Temp. $I_{CC} = f(T_{A}, V_{CC})$

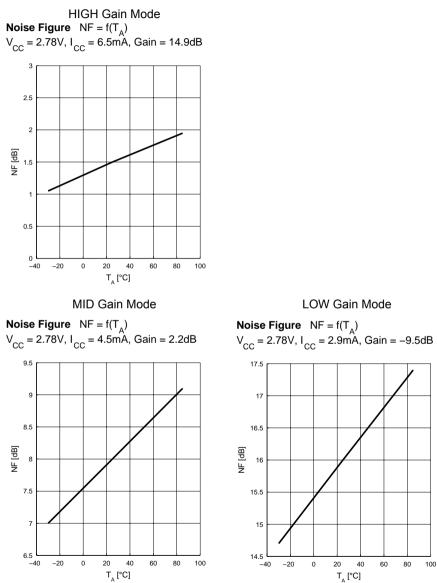


LOW Gain Mode $\label{eq:supply} \mbox{Supply current vs. Temp. } I_{\mbox{ } CC} = f(T_{\mbox{A}}, V_{\mbox{CC}})$



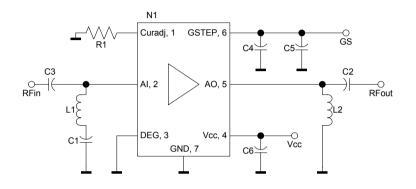


Typical measurement results Noise Figure





PCB Board Configuration

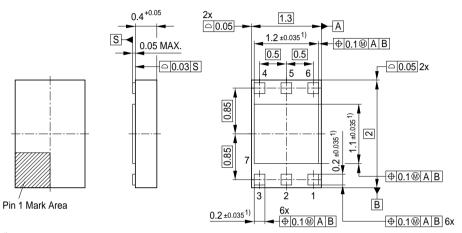


Bill of Materials

| Name | Value | Package | Manufacturer | Function |
|------|--------|------------|--------------|---|
| R1 | 15 kΩ | 0402 | various | bias resistance |
| L1 | 3.3 nH | 0402 | various | LF trap & input matching |
| L2 | 4.7 nH | 0402 | various | output matching |
| C1 | 10 nF | 0402 | various | LF trap |
| C2 | 10 pF | 0402 | various | DC block |
| C3 | 10 pF | 0402 | various | DC block |
| C4 | 10p | 0402 | various | control voltage filtering - OPTIONAL |
| C5 | 1 nF | 0402 | various | control voltage filtering - OPTIONAL |
| C6 | 1 nF | 0402 | | supply filtering |
| N1 | BGA619 | P-TSLP-7-1 | Infineon | SiGe LNA |
| | | | | |



Package Outline



¹⁾ Dimension applies to plated terminals

Tape & Reel Outline

